

Pulsed laser deposition of ZnS/FePt thin films on MgO (100) substrates <u>S. Macavei</u>, O. Pana, M. Stefan, D. Toloman, A. Popa, C. Leostean and L. Barbu-Tudoran



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INTRODUCTION

Ordered L1₀ FePt phase is a promising candidate for applications including biomaterials, permanent magnets, and spintronic devices

of nanoscale devices due its large magnetocrystalline anisotropy. ZnS is chosen as an additive to prepare FePt films in order to further

increase the degree of order and lower the annealing temperature.

EXPERIMENTAL

>ZnS/FePt thin films were grown on MgO (100) using PLD technique in different deposition conditions. The deposition parameters were for FePt: P=4.3 x 10^{-2} mbar, Ar atmosphere, T=700°C, 9600 pulses, 5 Hz. For ZnS the deposition parameters were: P=5.8 x 10^{-2} mbar, Ar atmosphere, T=450°C, 1200-2400-4800 pulses, 5 Hz.

X-ray diffraction (XRD) measurements were made using a Rigaku - SmartLab automated Multipurpose X-ray Diffractometer .
SEM Scanning Electron Microscopy was done using a HITACHI SU-8230.

>The magnetic properties were measured by SQUID MPMSXL magnetometer system.



CONCLUSIONS

- > We have deposited a series of ZnS/FePt/MgO(100) thin films using PLD technique.
- >Optimal parameters were identified in order to obtain ZnO/FePt/MgO(100) thin film without secondary phases.
- No diffraction peaks from other impurities are found within the detection limit.
- \geq EDX analysis showed the deposition of a uniform layer of FePt with L1₀ composition.
- ➢RHEED patterns are observed revealing an epitaxial growth of ZnS thin layer.
- ➢The magnetic properties are influenced by the magnetic coupling between ZnS and FePt layers; the coercive field varies one order of magnitude from 2260 to 23400 Oe in case of out of plane configuration.
- ➢The best deposition parameters were for FePt: P=4.3 x 10⁻² mbar, Ar atmosphere, T=700°C, 9600 pulses, 5 Hz. For
- ZnS the best deposition parameters were: P=5.8 x 10⁻² mbar, Ar atmosphere, T=450°C, 2400 pulses, 5 Hz.

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